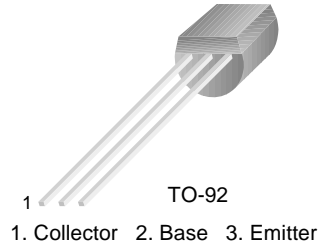


## BC556/557/558/559/560

### Switching and Amplifier

- High Voltage: BC556,  $V_{CE0} = -65V$
- Low Noise: BC559, BC560
- Complement to BC546 ... BC 550



### PNP Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_a = 25^\circ C$ unless otherwise noted

| Symbol    | Parameter                   | Value     | Units      |
|-----------|-----------------------------|-----------|------------|
| $V_{CBO}$ | Collector-Base Voltage      |           |            |
|           | : BC556                     | -80       | V          |
|           | : BC557/560                 | -50       | V          |
|           | : BC558/559                 | -30       | V          |
| $V_{CEO}$ | Collector-Emitter Voltage   |           |            |
|           | : BC556                     | -65       | V          |
|           | : BC557/560                 | -45       | V          |
|           | : BC558/559                 | -30       | V          |
| $V_{EBO}$ | Emitter-Base Voltage        | -5        | V          |
| $I_C$     | Collector Current (DC)      | -100      | mA         |
| $P_C$     | Collector Power Dissipation | 500       | mW         |
| $T_J$     | Junction Temperature        | 150       | $^\circ C$ |
| $T_{STG}$ | Storage Temperature         | -65 ~ 150 | $^\circ C$ |

#### Electrical Characteristics $T_a = 25^\circ C$ unless otherwise noted

| Symbol         | Parameter                            | Test Condition                         | Min.                                   | Typ. | Max. | Units |
|----------------|--------------------------------------|--|--|------|------|-------|
| $I_{CBO}$      | Collector Cut-off Current            | $V_{CB} = -30V, I_E = 0$               |  |      | -15  | nA    |
| $h_{FE}$       | DC Current Gain                      | $V_{CE} = -5V, I_C = 2mA$              | 110                                    |      | 800  |       |
| $V_{CE} (sat)$ | Collector-Emitter Saturation Voltage | $I_C = -10mA, I_B = -0.5mA$            |  | -90  | -300 | mV    |
|                |                                      | $I_C = -100mA, I_B = -5mA$             |  | -250 | -650 | mV    |
| $V_{BE} (sat)$ | Collector-Base Saturation Voltage    | $I_C = -10mA, I_B = -0.5mA$            |  | -700 |      | mV    |
|                |                                      | $I_C = -100mA, I_B = -5mA$             |  | -900 |      | mV    |
| $V_{BE} (on)$  | Base-Emitter On Voltage              | $V_{CE} = -5V, I_C = -2mA$             | -600                                   | -660 | -750 | mV    |
|                |                                      | $V_{CE} = -5V, I_C = -10mA$            |  |      | -800 | mV    |
| $f_T$          | Current Gain Bandwidth Product       | $V_{CE} = -5V, I_C = -10mA, f = 10MHz$ |  | 150  |      | MHz   |
| $C_{ob}$       | Output Capacitance                   | $V_{CB} = -10V, I_E = 0, f = 1MHz$     |  |      | 6    | pF    |
| NF             | Noise Figure                         | : BC556/557/558                        |  | 2    | 10   | dB    |
|                |                                      | : BC559/560                            | $f = 1KHz, R_G = 2K\Omega$             | 1    | 4    | dB    |
|                |                                      | : BC559                                | $V_{CE} = -5V, I_C = -200\mu A$        | 1.2  | 4    | dB    |
|                |                                      | : BC560                                | $R_G = 2K\Omega, f = 30 \sim 15000MHz$ | 1.2  | 2    | dB    |

### $h_{FE}$ Classification

| Classification | A         | B         | C         |
|----------------|-----------|-----------|-----------|
| $h_{FE}$       | 110 ~ 220 | 200 ~ 450 | 420 ~ 800 |

# Typical Characteristics

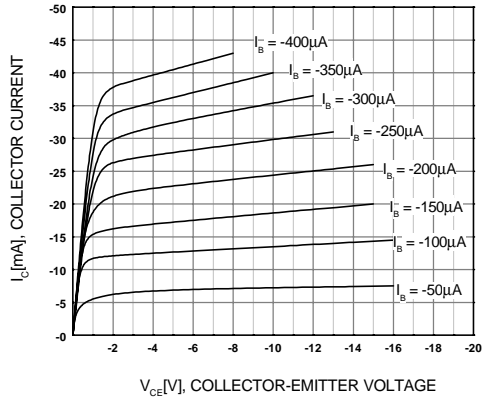


Figure 1. Static Characteristic

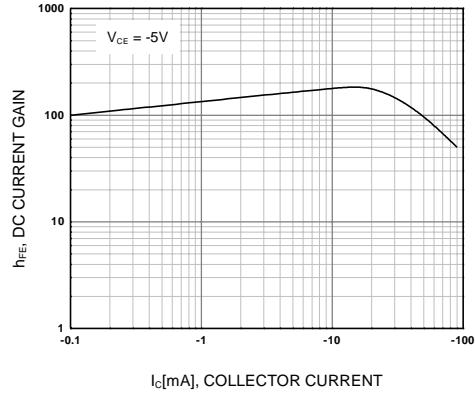


Figure 2. DC current Gain

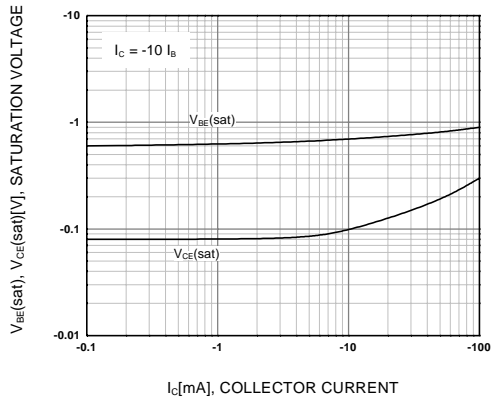


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

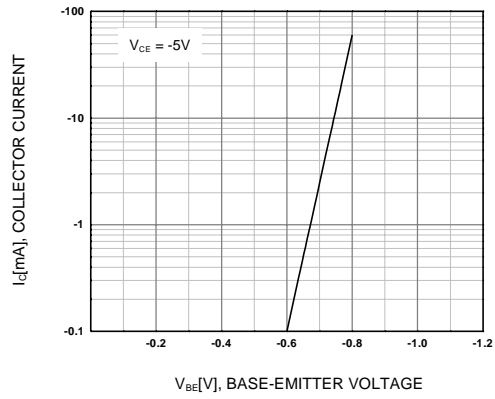


Figure 4. Base-Emitter On Voltage

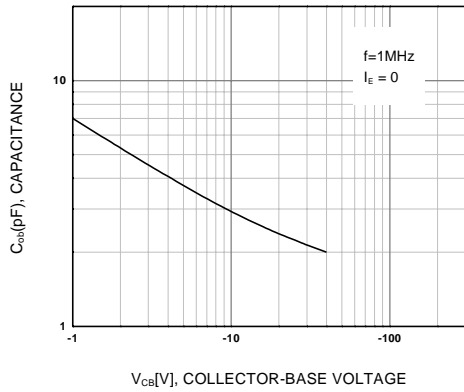


Figure 5. Collector Output Capacitance

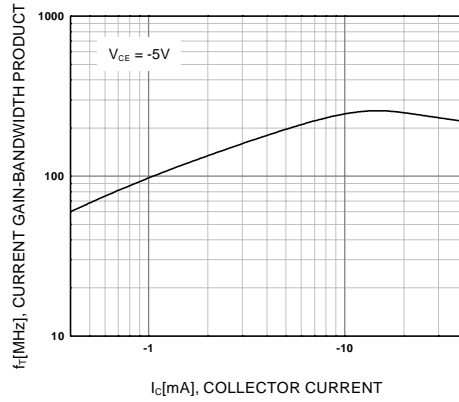
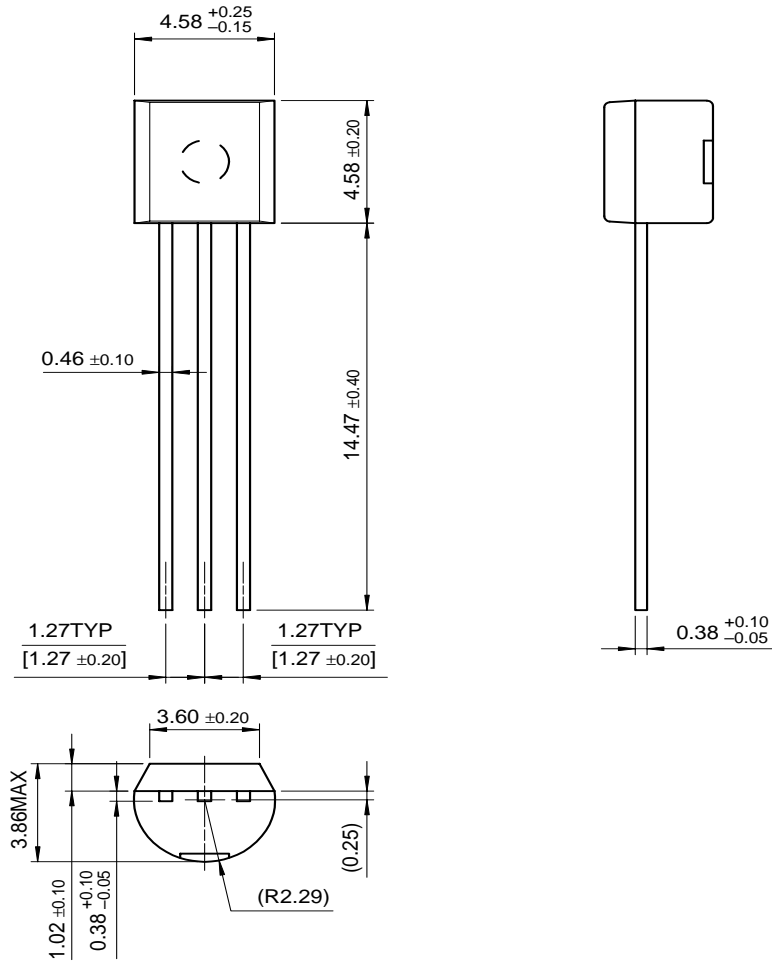


Figure 6. Current Gain Bandwidth Product

# Package Dimensions

## TO-92



Dimensions in Millimeters

BC556/557/558/559/560

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